

Confinement and flow dynamics in thin polymer films for nanoimprint lithography

J. Teisseire, E. Revaux, M. Foresti, E. Barthel

▶ To cite this version:

J. Teisseire, E. Revaux, M. Foresti, E. Barthel. Confinement and flow dynamics in thin polymer films for nanoimprint lithography. Applied Physics Letters, 2011, 98, pp.013106. 10.1063/1.3535614 . hal-00553474

HAL Id: hal-00553474 https://hal.science/hal-00553474v1

Submitted on 10 Jan 2011

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers. L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

Confinement and flow dynamics in thin polymer films for nanoimprint lithography

Jérémie Teisseire, Amélie Revaux, Maud Foresti, and Etienne Barthel^{a)} Surface du Verre et Interfaces, UMR 125 CNRS/Saint-Gobain, 39 quai Lucien Lefranc, BP 135, F-93303 Aubervilliers Cedex, France

(Received 6 July 2010; accepted 17 December 2010; published online 6 January 2011)

In nanoimprint lithography (NIL) viscous flow in polymeric thin films is the primary mechanism for the generation and the relaxation of the structures. Here we quantify the impact of confinement on the flow rate. Pattern relaxation experiments were carried out above the glass transition temperature as a function of film thickness. The results are adequately fitted by a simple expression for the flow rate valid at all confinements. This expression, based on Newtonian viscosity, should be of use in NIL process design and for the measurement of the rheological properties of confined polymers. © 2011 American Institute of Physics. [doi:10.1063/1.3535614]

Surface textures offer an interesting paradigm for advanced properties in the areas of optics,¹ adhesion,² and wetting.³ Efficient processes must be found for fast and low cost production of elaborate surface textures on large substrates. Nanoimprint lithography (NIL) potentially fulfills these requirements.^{4–9} When pressing a textured mold onto a soft film (resist) deposited on the surface, the film material flows into the mask features. If the system is crosslinked or quenched before the mold is released, permanent surface features are obtained. Material flow in viscous thin films is the primary mechanism for the generation and the relaxation of the structures.

The effect of confinement on the flow in thin films is twofold. On the one hand it has been demonstrated that the intrinsic rheological properties of polymers may be altered by confinement due to modifications of structure of the material close to interfaces.^{10–14} On the other hand, confinement will also directly impact the flow pattern. This parameter is prominent in a number of numerical studies of embossing^{15,16} but there is still a good deal of confusion over this issue. On the one hand, some studies of NIL reflow^{17,18} completely neglect the direct impact of confinement on flow rate. On the other hand a model has recently been developed, based on the lubrication approximation¹⁹ but its validity in realistic cases has not been assessed. In this paper we measure the impact of confinement on the reflow of structures imprinted on a low molecular weight polymer and propose a simple analytic model valid in all confinement regimes to account for the data.

The experiments were carried out on poly(methyl methacrylate) (PMMA) (Sigma-Aldrich, St Quentin Fallavier) $[M_w=15 \text{ kg/mol}, \text{ entanglement molecular weight } (M_e = 10 \text{ kg/mol}), \text{ bulk } T_g=96 ^{\circ}\text{C}]$. The bulk viscosity was measured on macroscopic pellets by oscillatory frequency sweep and strain sweep ($\eta_{\text{bulk}}=1.2 \times 10^7$ Pa s at 120 °C and 4.5×10^5 Pa s at 130 °C). Thin films were spin-coated onto clean Si(100) wafers. Thicknesses *H* (0.2, 0.3, 0.4, 1.0, 1.4, and 2.0 μ m) were adjusted by dilution in methyl-isobutylketone. The residual stresses and residual solvent in the film were minimized by annealing at 170 °C during 20 min and cooling down to room temperature in 4 h. A rectangular grating (wavelength $\lambda \equiv 2\pi/k = 1.5 \ \mu$ m, amplitude $2h_0 = 50 \ nm$) was generated by nanoimprint lithography using a 1 cm^2 polydimethylsiloxane (PDMS) stamp. The stamp was applied on the film with a 50 N load, and imprint was carried out at 170 °C for 1 h before cooling to room temperature in 15 min. The stamp was easily removed from the surface of the film. Atomic force microscopy (AFM) scans of the surfaces attest that the amplitude of the replica is equal to the mask feature amplitude. We then measured the relaxation rate of the structures at constant temperature (above the glass transition temperature T_g) as a function of film thickness. Series of samples were annealed at $T_r = 120 \text{ °C}$ or T_r =130 °C and quenched to room temperature at regular intervals. The final profiles were measured by AFM (Fig. 1). We found that the modulation amplitude decreases exponentially as observed previously^{17,18,20} and that the relaxation rate decreases strongly when the thickness of the layer decreases.

The driving force for relaxation is the Laplace pressure due to the curvature of the surface with surface tension γ . For small modulation amplitude $h(t)\sin(kx)$ the modulation is expected to decrease exponentially with rate τ^{-1} , which is consistent with the observations. For a half-space (unconfined relaxation) it is found¹² that



FIG. 1. Decay of structure amplitude 2h as a function of annealing time for various film thicknesses. The amplitudes are normalized by the initial value 2h(0)=50 nm. The annealing temperature is $T_r=120$ °C. The straight lines are exponential fits from which the relaxation rate as a function of film thickness is derived.

98, 013106-1

© 2011 American Institute of Physics

Author complimentary copy. Redistribution subject to AIP license or copyright, see http://apl.aip.org/apl/copyright.jsp

^{a)}Electronic mail: etienne.barthel@saint-gobain.com.



FIG. 2. Normalized flow rate measured in relaxation experiments performed at $T_r=120$ °C (open square) and at $T_r=130$ °C (closed square) are plotted as a function of normalized film thickness. Models: lubrication approximation [Eq. (2), plain line] and full confinement model [Eq. (3), dashed line].

$$\tau_{\infty}^{-1} = \frac{\gamma k}{2\eta}.$$
 (1)

To account for the marked drop of the relaxation rate with decreasing film thickness, we considered the lubrication approximation¹⁹ which predicts a very sharp reduction of the relaxation rate τ_{lub}^{-1} with confinement

$$\tau_{\rm lub}^{-1} = \frac{3}{2} (kH)^3 \tau_{\infty}^{-1}.$$
 (2)

Figure 2 compares the measured relaxation rates as a function of normalized film thickness kH for annealing temperatures equal to T_r =120 and 130 °C with the predictions from the lubrication approximation, which demonstrates that a more complete model is needed. Following Huang,²¹ we have developed a two-dimensional model assuming Newtonian viscosity. No-slip boundary conditions at the interface with the solid were assumed due to strong anchoring of PMMA on the silicon surface.^{22,23} For arbitrary confinement, the relaxation rate is found to scale down from the unconfined relaxation rate τ_{∞}^{-1} as $\tau^{-1} = \mathcal{R}(kH)\tau_{\infty}^{-1}$, where

$$\mathcal{R}(kH) = \frac{\exp(2kH) - \exp(-2kH) - 4kH}{\exp(-2kH) + 2 + \exp(2kH) + 4(kH)^2},$$
(3)

which is typical for two interacting parallel interfaces.^{24,25} In the half-space limit $\mathcal{R}(kH)$ goes to 1 (unconfined) while Eq. (2) is recovered for small kH.

Comparing Eq. (2) and Eq. (3) (Fig. 2), we find that the lubrication approximation is valid for small wave vectors kH < 0.3, i.e., for feature periods large compared to the film thickness $H < \lambda/20$. For a less severe confinement the relaxation rate grows more slowly than $(kH)^3$ finally saturating at the unconfined limit τ_{∞}^{-1} when 3 < kH (or $\lambda < 2H$). $\mathcal{R}(kH)$ fits our data reasonably well with no other adjustable parameter than the unconfined flow rate [Eq. (1)]. Using a surface tension²⁶ γ =41 mJ m⁻² we infer viscosities $\eta_{relax}=5.2 \times 10^7$ Pa s for PMMA at 120 °C and $\eta_{relax}=6.0 \times 10^6$ Pa s at 130 °C.

Reasonably good agreement is obtained although the reduction of the flow rate in the confined regime is somewhat more progressive than the simple Newtonian fluid prediction. We note that the material viscosity evaluated from the fit, which mainly reflects the flow rate in the thick film limit $kH \ge 1$, is one order of magnitude higher than the measured bulk viscosity, quite similar to other literature results.²⁷ Although the T_g of such thick films is not expected to be affected by interface effects,^{10,14} film material may differ from



FIG. 3. Horizontal component of the velocity profile at x=0 for unconfined flow (kH=10), intermediate confinement (kH=1), and confined flow (kH=0.1, inset). The flow profiles directly illustrate the transition between half space flow distribution with penetration depth of the order of the pattern period to the parabolic profile characteristic of the lubrication approximation.

bulk due to fast drying conditions during spin coating, short annealing time²⁸ and possible impact of the embossing process, such as diffusion of the smaller PMMA molecules in the PDMS stamp. However the differences *between* films should be limited, so that it is the thickness variation which primarily impacts the flow rate and Eq. (3) provides an adequate approximation for the impact of confinement as shown on Fig. 2.

Impact of confinement can be visualized on representative horizontal velocity profiles taken at x=0 where the horizontal component of the velocity is maximum (Fig. 3). For large values of kH (here for kH=10) the flow extends into the film over a penetration depth commensurate with the period λ and the interface does not impact the flow distribution. Confinement (here for kH=1) results in a marked distortion of the flow, pushing the flow maximum to the surface and resulting in a drop of the flow rate (Fig. 2). Severe confinement (kH=0.1) results in the quadratic in-plane velocity distribution characteristic of the lubrication approximation. We insist that the relevant measure of confinement is the ratio of the feature wavelength to the film thickness (kH)⁻¹. In contrast, the structure amplitude h(0) does not impact the relaxation rate at this level of modeling.

As a conclusion, we have demonstrated that direct confinement effects on the flow pattern can be taken into account in flow rate prediction using a simple analytic formula for the flow rate. This equation holds for all degrees of confinement, including many realistic NIL configurations. The model has been validated through flow rate measurements as a function of film thickness. It may be used for flow rate assessment both for structure stability against reflow and for material flow into the structures during embossing or to identify dominant flow modes.¹⁶ In another area, it may also be of use for the assessment of the rheological properties of very thin polymeric films per se.

We thank Stéphane Roux, Elin Søndergård, and Aurélie Papon for suggestions and help, and the EU FP7 NapaNIL project (Contract No. NMP2-LA-2008-214249) for funding.

Author complimentary copy. Redistribution subject to AIP license or copyright, see http://apl.aip.org/apl/copyright.jsp

¹S. B. Rim, S. Zhao, S. R. Scully, M. D. McGehee, and P. Peumans, Appl. Phys. Lett. **91**, 243501 (2007).

²M. Lamblet, E. Verneuil, T. Vilmin, A. Buguin, P. Silberzan, and L. Leger, Langmuir **23**, 6966 (2007).

³A. Tuteja, W. Choi, J. Mabry, G. McKinley, and R. Cohen, Proc. Natl. Acad. Sci. U.S.A. **105**, 18200 (2008).

- ⁴S. Chou, P. Krauss, and P. Renstrom, Appl. Phys. Lett. 67, 3114 (1995).
- ⁵G. Cross, J. Phys. D **39**, R363 (2006).
- ⁶L. J. Guo, Adv. Mater. (Weinheim, Ger.) **19**, 495 (2007).
- ⁷H. Schift, J. Vac. Sci. Technol. B 26, 458 (2008).
- ⁸C. Peroz, C. Heitz, E. Barthel, E. Søndergård, and V. Goletto, J. Vac. Sci. Technol. B **25**, L27 (2007).
- ⁹C. Peroz, V. Chauveau, E. Barthel, and E. Sondergard, Adv. Mater. (Weinheim, Ger.) **21**, 555 (2009).
- ¹⁰J. A. Forrest, K. Dalnoki-Veress, and J. R. Dutcher, Phys. Rev. E **56**, 5705 (1997).
- ¹¹M. Hamdorf and D. Johannsmann, J. Chem. Phys. **112**, 4262 (2000).
- ¹²K. Petersen and D. Johannsmann, J. Non-Cryst. Solids 307–310, 532 (2002).
- ¹³M. Mundra, S. Donthu, V. Dravid, and J. Torkelson, Nano Lett. 7, 713 (2007).
- ¹⁴Z. Fakhraai and J. A. Forrest, Science **319**, 600 (2008).
- ¹⁵H. D. Rowland and W. P. King, J. Micromech. Microeng. 14, 1625 (2004).
- ¹⁶H. D. Rowland, A. C. Sun, P. R. Schunk, and W. P. King, J. Micromech.

Microeng. 15, 2414 (2005).

- ¹⁷Y. Ding, H. W. Ro, T. Germer, J. Douglas, B. Okerberg, A. Karim, and C. Soles, ACS Nano 1, 84 (2007).
- ¹⁸Y. Ding, H. W. Ro, J. Douglas, R. Jones, D. Hine, A. Karim, and C. Soles, Adv. Mater. (Weinheim, Ger.) **19**, 1377 (2007).
- ¹⁹T. Leveder, S. Landis, and L. Davoust, Appl. Phys. Lett. **92**, 013107 (2008).
- ²⁰H.-G. Peng, Y. P. Kong, and A. F. Yee, Macromolecules **43**, 409 (2010).
- ²¹R. Huang and Z. Suo, Int. J. Solids Struct. **39**, 1791 (2002).
- ²²J. Keddie, R. Jones, and R. Cory, EPL **27**, 59 (1994).
- ²³L. Xue and Y. Han, Langmuir **25**, 5135 (2009).
- ²⁴A. Perriot and E. Barthel, J. Mater. Res. **19**, 600 (2004).
- ²⁵E. Barthel, A. Perriot, A. Chateauminois, and C. Frétigny, Philos. Mag. 86, 5359 (2006).
- ²⁶S. Wu, Polymer Interface and Adhesion (Marcel Dekker, New York, 1982).
- ²⁷R. Jones, T. Hu, C. Soles, E. Lin, R. Reano, S. Pang, and D. Casa, Nano Lett. 6, 1723 (2006).
- ²⁸D. Barbero and U. Steiner, Phys. Rev. Lett. **102**, 248303 (2009).